Ultrafast Diode

80 A, 1000 V

RURG80100

Description

The RURG80100 is an ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery, $t_{rr} = 200 \text{ ns} (@ I_F = 80 \text{ A})$
- Max Forward Voltage, $V_F = 1.9 V (@ T_C = 25 °C)$
- 1000 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

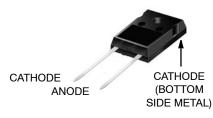
Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	1000	V
Working Peak Reverse Voltage	V _{RWM}	1000	V
DC Blocking Voltage	V _R	1000	V
Average Rectified Forward Current (T _C = 53 $^{\circ}$ C)	I _{F(AV)}	80	A
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I _{FRM}	160	A
Nonrepetitive Peak Surge Current (Halfwave 1 Phase, 60 Hz)	I _{FSM}	500	A
Maximum Power Dissipation	PD	180	W
Avalanche Energy (See Figure 7 and Figure 8)	E _{AVL}	50	mJ
Operating and Storage Temperature	T _{STG,} T _J	–65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

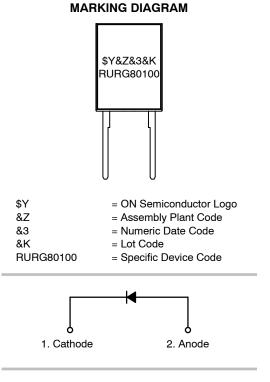


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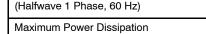


JEDEC STYLE 2 LEAD TO-247 340CL



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.



RURG80100

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Package	Brand	
RURG80100	TO-247-2L	RURG80100	

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
	Instantaneous Forward Voltage (Pulse Width = 300 μs, Duty Cycle = 2%)	I _F = 80 A			1.9	V
		I _F = 80 A, T _C = 150°C			1.7	V
I _R	Instantaneous Reverse Current	V _R = 1000 V			250	μΑ
		V _R = 1000 V T _C = 150°C			2	mA
T _{rr} Reverse Recovery Time (See Figure Summation of t _a + t _b	Reverse Recovery Time (See Figure 6) Summation of t_a + t_b	I _F = 1 A, dI _F /dt = 100 A/μs			125	ns
		I _F = 80 A, dI _F /dt = 100 A/μs			200	ns
t _a	Time to Reach Peak Reverse Current (See Figure 6)	I _F = 80 A, dI _F /dt = 100 A/μs		90		ns
t _b	Time from Peak I_{RM} to Projected Zero Crossing of I_{RM} Based on a Straight Line from Peak I_{RM} Through 25% of I_{RM} (See Figure 6)	I _F = 80 A, dI _F /dt = 100 A/μs		65		ns
$R_{\theta JC}$	Thermal Resistance Junction to Case				0.83	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

RURG80100

TYPICAL PERFORMANCE CURVES

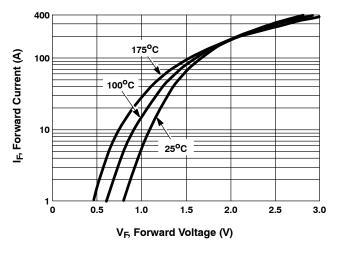


Figure 1. Forward Current vs. Forward Voltage

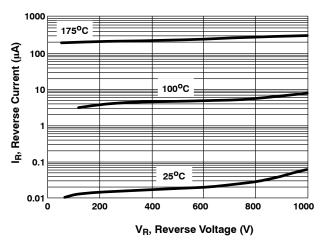


Figure 2. Reverse Current vs. Reverse Voltage

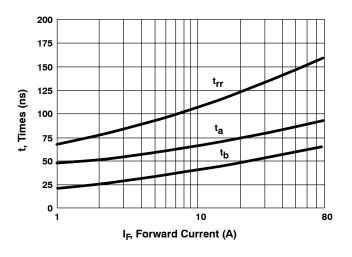


Figure 3. $t_{rr},\,t_a$ and t_b Curves vs. Forward Current

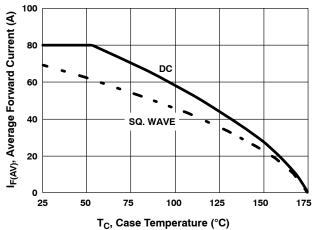
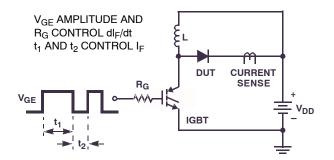


Figure 4. Current Derating Curve

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TEST CIRCUITS AND WAVEFORMS





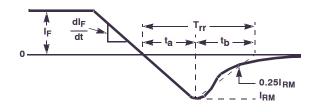


Figure 6. T_{rr} Waveforms and Definitions

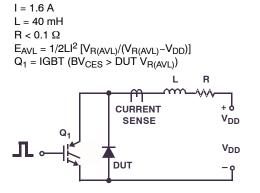


Figure 7. Avalanche Energy Test Circuit

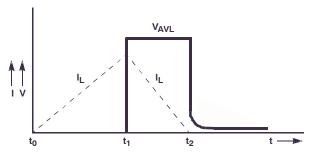


Figure 8. Avalanche Current and Voltage Waveforms

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MILLIMETERS

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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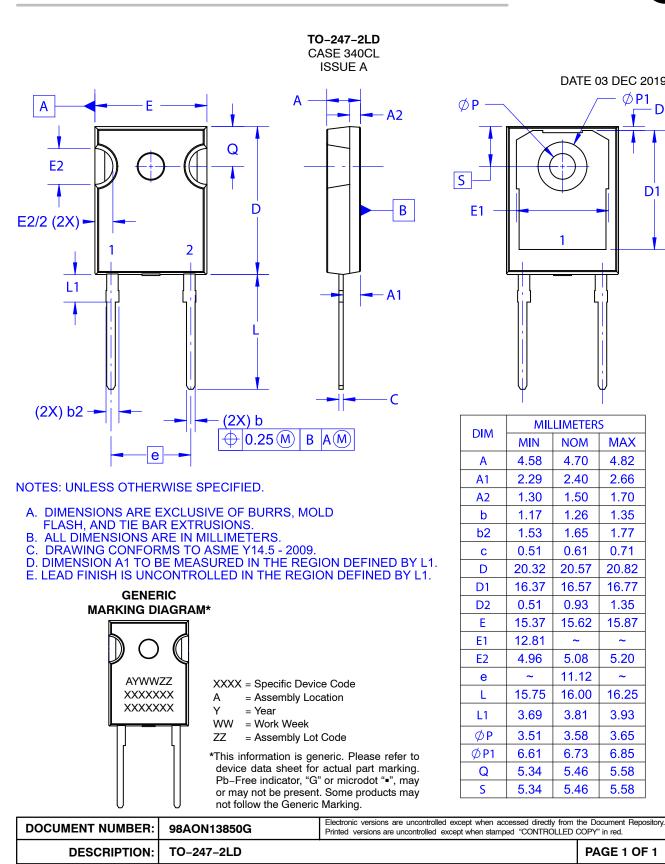
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